

TSL2591

Light-to-Digital Converter

General Description

The TSL2591 is a very-high sensitivity light-to-digital converter that transforms light intensity into a digital signal output capable of direct I²C interface. The device combines one broadband photodiode (visible plus infrared) and one infrared-responding photodiode on a single CMOS integrated circuit. Two integrating ADCs convert the photodiode currents into a digital output that represents the irradiance measured on each channel. This digital output can be input to a microprocessor where illuminance (ambient light level) in lux is derived using an empirical formula to approximate the human eye response. The TSL2591 supports a traditional level style interrupt that remains asserted until the firmware clears it.

Ordering Information and Content Guide appear at end of datasheet.

Figure 1: Added Value of Using TSL2591

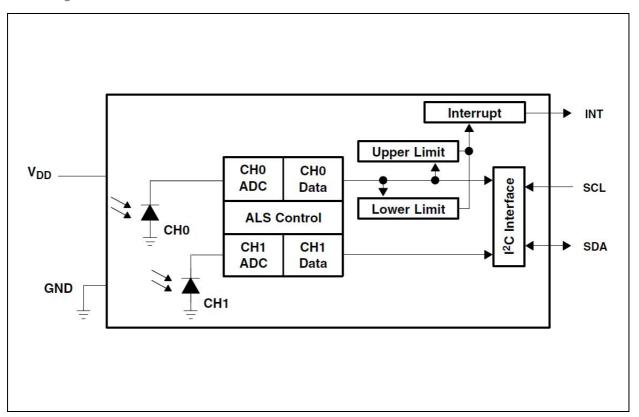
Benefits	Features
Approximates Human Eye Response	Dual Diode
Flexible Operation	Programmable Analog Gain and Integration Time
Suited for Operation Behind Dark Glass	600M:1 Dynamic Range
Low Operating Overhead	 Two Internal Interrupt Sources Programmable Upper and Lower Thresholds One Interrupt Includes Programmable Persistence Filter
Low Power 3.0 μA Sleep State	User Selectable Sleep Mode
I ² C Fast Mode Compatible Interface	 Data Rates up to 400 kbit/s Input Voltage Levels Compatible with 3.0V Bus



Block Diagram

The functional blocks of this device are shown below:

Figure 2: Block Diagram



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Detailed Description

The TSL2591 contains two integrating analog-to-digital converters (ADC) that integrate currents from two photodiodes. Integration of both channels occurs simultaneously. Upon completion of the conversion cycle, the conversion result is transferred to the Channel 0 and Channel 1 data registers, respectively. The transfers are double-buffered to ensure that the integrity of the data is maintained. After the transfer, the device automatically begins the next integration cycle.

Communication with the device is accomplished through a standard, two-wire I²C serial bus. Consequently, the TSL2591 can be easily connected to a microcontroller or embedded controller. No external circuitry is required for signal conditioning. Because the output of the device is digital, the output is effectively immune to noise when compared to an analog signal.

The TSL2591 also supports an interrupt feature that simplifies and improves system efficiency by eliminating the need to poll a sensor for a light intensity value. The primary purpose of the interrupt function is to detect a meaningful change in light intensity. The concept of a meaningful change can be defined by the user both in terms of light intensity and time, or persistence, of that change in intensity. The device has the ability to define two sets of thresholds, both above and below the current light level. An interrupt is generated when the value of a conversion exceeds either of these limits. One set of thresholds can be configured to trigger an interrupt only when the ambient light exceeds them for a configurable amount of time (persistence) while the other set can be configured to trigger an immediate interrupt.

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Pin Assignment

The TSL2591 pin assignments are described below.

Figure 3: Pin Diagram

Package FN Dual Flat No-Lead (Top View): Package drawing is not to scale.

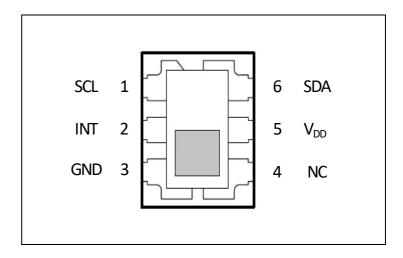


Figure 4: Pin Description

Pin Number	Pin Name	Description
1	SCL	I ² C serial clock input terminal
2	INT	Interrupt — open drain output (active low).
3	GND	Power supply ground. All voltages are referenced to GND.
4	NC	No connect — do not connect.
5	V _{DD}	Supply voltage
6	SDA	I ² C serial data I/O terminal

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Absolute Maximum Ratings

Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only. Functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Figure 5: Absolute Maximum Ratings

Parameter	Min	Max	Units	Comments
Supply voltage, V _{DD}		3.8	V	All voltages are with respect to GND
Input terminal voltage	-0.5	3.8	V	
Output terminal voltage	-0.5	3.8	V	
Output terminal current	-1	20	mA	
Storage temperature range, T _{stg}	-40	85	°C	
ESD tolerance, human body model	±2000		V	JESD22-A114-B
ESD tolerance, charge device model (CDM)	±5	00	V	JESD22-C101

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Electrical Characteristics

All limits are guaranteed. The parameters with min and max values are guaranteed with production tests or SQC (Statistical Quality Control) methods. Device parameters are guaranteed at $T_A = 25^{\circ}\text{C}$ unless otherwise noted.

Figure 6: Recommended Operating Conditions

Symbol	Parameter	Min	Тур	Max	Units
V _{DD}	Supply voltage	2.7	3	3.6	V
T _A	Operating free-air temperature	-30		70	°C

Figure 7: Operating Characteristics, V_{DD} =3V, T_A =25°C (unless otherwise noted)

Symbol	Parameter	Conditions	Min	Тур	Max	Units	
I _{DD}	Supply current	Active Sleep state - no I ² C activity		275 2.3	325 4	μΑ	
V _{OL}	INT, SDA output low voltage	3mA sink current 6mA sink current	0 0		0.4 0.6	٧	
I _{LEAK}	Leakage current, SDA, SCL, INT pins		-5		5	μΑ	
V _{IH}	SCL, SDA input high voltage	TSL25911 (V _{bus} = V _{DD})	0.7 V _{DD}			V	
VIH.		TSL25913 (V _{bus} = 1.8)	1.26			V	
V _{IL}	SCL, SDA input low	TSL25911 ($V_{bus} = V_{DD}$)			0.3 V _{DD}	V	
- IL	voltage	TSL25913 (V _{bus} = 1.8)			0.54	V	

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Figure 8: ALS Characteristics, V_{DD} =3V, T_A =25 °C, AGAIN = High, AEN=1, (unless otherwise noted)^{(1) (2) (3)}

Parameter	Conditions	Channel	Min	Тур	Max	Units
Dark ADC count value	E _e = 0, AGAIN = Max, ATIME=000b (100ms)	CH0 CH1	0 0		20 20	counts
ADC integration time step size	ATIME = 000b (100ms)		95	100	105	ms
ADC number of integration steps (4)			1		6	steps
Max ADC count	ATIME = 000b (100ms)		0		36863	counts
Max ADC count	ATIME = 001b (200ms), 010b (300ms), 011b (400ms), 100b (500ms), 101b (600ms)		0		65535	counts
	White light $^{(2)}$ $E_e = 4.98 \mu \text{W/cm}^2$ ATIME = 000b (100 ms)	CH0 CH1	1120	1315 174	1510	counts
ADC count value	$\lambda_p = 850 \text{ nm}^{(3)}$ $E_e = 5.62 \mu\text{W/cm}^2,$ ATIME = 000b (100 ms)	CH0 CH1	1230	1447 866	1665	counts
ADC count value	White light ⁽²⁾		0.092	0.132	0.172	
ratio: CH1/CH0	$\lambda_{p} = 850 \text{ nm}^{(3)}$		0.558	0.598	0.638	
R _e	White light ⁽²⁾ ATIME = 000b (100 ms)	CH0 CH1		264.1 34.9		counts/
Irradiance responsivity	$\lambda_p = 850 \text{ nm}^{(3)}$ ATIME = 000b (100 ms)	CH0 CH1		257.5 154.1		(μW/cm ²)
Noise ⁽⁴⁾	White light $^{(2)}$ $E_e = 4.98 \mu \text{W/cm}^2$ ATIME = 000b (100 ms)	СН0		1	2	1 standard deviation

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Parameter	Conditions	Channel	Min	Тур	Max	Units
Gain scaling, relative to 1× gain setting (AGAIN = Low)	AGAIN = Med	CH0 CH1	22 22	24.5 24.5	27 27	
	AGAIN = High	CH0 CH1	360 360	400 400	440 440	×
	AGAIN = Max	CH0 CH1	8500 9100	9200 9900	9900 10700	

Note(s):

- 1. Optical measurements are made using small-angle incident radiation from light-emitting diode optical sources. Visible white LEDs and infrared 850 nm LEDs are used for final product testing for compatibility with high-volume production
- 2. The white LED irradiance is supplied by a white light-emitting diode with a nominal color temperature of 4000 K.
- 3. The 850 nm irradiance is supplied by a GaAs light-emitting diode with the following typical characteristics: peak wavelength $\lambda_p = 850$ nm and spectral halfwidth $\Delta\lambda 1/2 = 42$ nm.
- 4. Parameter ensured by design and is not 100% tested.

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Timing Characteristics

The timing characteristics of TSL2591 are given below.

Figure 9:

AC Electrical Characteristics, $V_{DD} = 3 \text{ V}$, $T_A = 25$ °C (unless otherwise noted)

Parameter ⁽¹⁾	Description	Min	Тур	Max	Units
f _(SCL)	Clock frequency (I ² C only)	0		400	kHz
t _(BUF)	Bus free time between start and stop condition	1.3			μs
t _(HDSTA)	Hold time after (repeated) start condition. After this period, the first clock is generated.	0.6			μs
t _(SUSTA)	Repeated start condition setup time	0.6			μs
t _(SUSTO)	Stop condition setup time	0.6			μs
t _(HDDAT)	Data hold time	0			μs
t _(SUDAT)	Data setup time	100			ns
t _(LOW)	SCL clock low period	1.3			μs
t _(HIGH)	SCL clock high period	0.6			μs
t _F	Clock/data fall time			300	ns
t _R	Clock/data rise time			300	ns
C _i	Input pin capacitance			10	pF

Note(s):

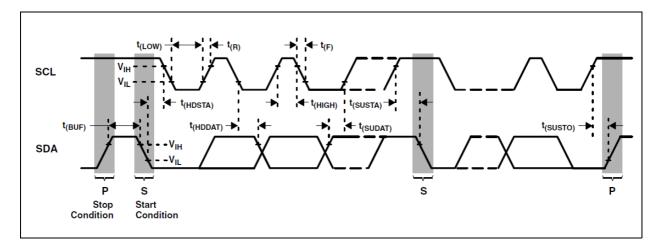
1. Specified by design and characterization; not production tested.

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Timing Diagrams

Figure 10: Parameter Measurement Information



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Typical Operating Characteristics

Spectral Responsivity: Two channel response allows for tunable illuminance (lux) calculation regardless of transmissivity of glass.

Figure 11: Spectral Responsivity

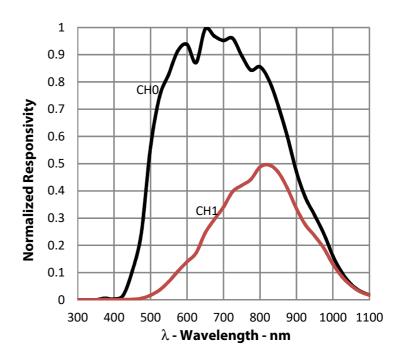
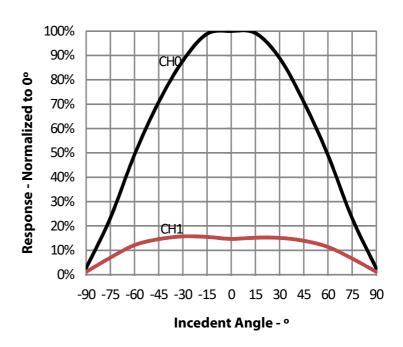


Figure 12: White Normalized Responsivity vs. Angular Displacement

White LED Angular Response: Near cosine angular response for broadband white light sources.



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I_{DD} vs. V_{DD} and Temp: Effect of supply voltage and temperature on active current.

Figure 13: Normalized I_{DD} vs. V_{DD} and Temperature

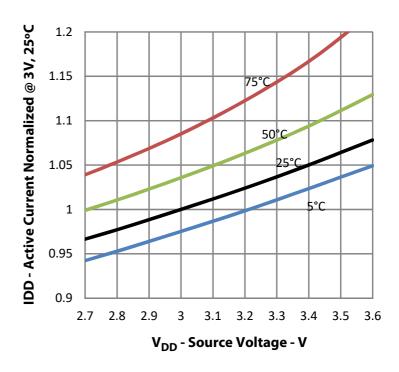
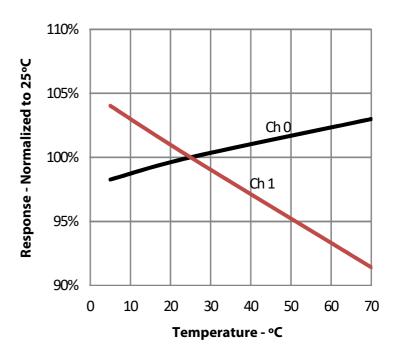


Figure 14:
Response to White LED vs. Temperature

White LED Response vs. Temp: Effect of temperature on the device response for a broadband white light source.



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Register Description

The device is controlled and monitored by registers accessed through the I²C serial interface. These registers provide for a variety of control functions and can be read to determine results of the ADC conversions. The register set is summarized in Figure 15.

Figure 15: Register Description

Address	Register Name	R/W	Register Function	Reset Value
	COMMAND	W	Specifies Register Address	0x00
0x00	ENABLE	R/W	Enables states and interrupts	0x00
0x01	CONFIG	R/W	ALS gain and integration time configuration	0x00
0x04	AILTL	R/W	ALS interrupt low threshold low byte	0x00
0x05	AILTH	R/W	ALS interrupt low threshold high byte	0x00
0x06	AIHTL	R/W	ALS interrupt high threshold low byte	0x00
0x07	AIHTH	R/W	ALS interrupt high threshold high byte	0x00
0x08	NPAILTL	R/W	No Persist ALS interrupt low threshold low byte	0x00
0x09	NPAILTH	R/W	No Persist ALS interrupt low threshold high byte	0x00
0x0A	NPAIHTL	R/W	No Persist ALS interrupt high threshold low byte	0x00
0x0B	NPAIHTH	R/W	No Persist ALS interrupt high threshold high byte	0x00
0x0C	PERSIST	R/W	Interrupt persistence filter	0x00
0x11	PID	R	Package ID	
0x12	ID	R	Device ID	ID
0x13	STATUS	R	Device status	0x00
0x14	CODATAL	R	CH0 ADC low data byte	0x00
0x15	CODATAH	R	CH0 ADC high data byte	0x00
0x16	C1DATAL	R	CH1 ADC low data byte	0x00
0x17	C1DATAH	R	CH1 ADC high data byte	0x00

Note(s):

1. Devices with a primary I^2C address of 0x29 also have a secondary I^2C address of 0x28 that can be used for read only registers to quickly read in a single block I^2C transaction.

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Command Register

The COMMAND register specifies the address of the target register for future read and write operations, as well as issues special function commands.

7 6 5 4 3 2 1 0

CMD TRANSACTION ADDR/SF

Fields	Bits	Description				
CMD	7	Select Command Register. Must write as 1 when addressing COMMAND register.				
		Select type of transa	action to follow in subsequent data transfers			
		FIELD VALUE	DESCRIPTION			
TDANICACTION	6.5	00	Reserved - Do not use			
TRANSACTION	6:5	01	Normal Operation			
		10	Reserved – Do not use			
		11	Special Function – See description below			
		Address field/special function field. Depending on the transaction type, see above, this field either specifies a special function command or selects the specific control-status-data register for subsequent read and write transactions. The field values listed below apply only to special function commands.				
		FIELD VALUE	DESCRIPTION			
		00100	Interrupt set – forces an interrupt			
		00110	Clears ALS interrupt			
ADDR/SF	4:0	00111	Clears ALS and no persist ALS interrupt			
		01010	Clears no persist ALS interrupt			
		other	Reserved – Do not write			
		in the status register INT pin, one of the ir (0x00) must be asser The interrupt set spe clear special function	ecial function command sets the interrupt bits (0x13). For the interrupt to be visible on the interrupt enable bits in the enable register rted. Ecial function must be cleared with an interrupt in. The ALS interrupt clear special functions iterrupt(s) and are self-clearing.			

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Enable Register (0x00)

The ENABLE register is used to power the device on/off, enable functions and interrupts.

7	6	5	4	3	2	1	0
NPIEN	SAI	Reserved	AIEN	Rese	rved	AEN	PON

Fields	Bits	Description
NPIEN	7	No Persist Interrupt Enable. When asserted NP Threshold conditions will generate an interrupt, bypassing the persist filter.
SAI	SAI Sleep after interrupt. When asserted, the device the end of an ALS cycle if an interrupt has been	
Reserved	5	Reserved. Write as 0.
AIEN	4	ALS Interrupt Enable. When asserted permits ALS interrupts to be generated, subject to the persist filter.
Reserved	3:2	Reserved. Write as 0.
AEN	1	ALS Enable. This field activates ALS function. Writing a one activates the ALS. Writing a zero disables the ALS.
PON	0	Power ON. This field activates the internal oscillator to permit the timers and ADC channels to operate. Writing a one activates the oscillator. Writing a zero disables the oscillator.

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Control Register (0x01)

The CONTROL register is used to configure the ALS gain and integration time. In addition, a system reset is provided. Upon power up, the CONTROL register resets to 0x00.

 7
 6
 5
 4
 3
 2
 1
 0

 SRESET
 Reserved
 AGAIN
 Reserved
 ATIME

Fields	Bits	Description		
SRESET	7	System reset. When asserted, the device will reset equivalent to a power-on reset. SRESET is self-clearing.		
Reserved	6	Reserved. Write as 0.		
		ALS gain sets the g	gain of the internal integrationels.	on amplifiers for both
		FIELD VALUE	DESCRIPT	TON
AGAIN	5:4	00	Low gain mode	
		01	Medium gain mode	
		10	High gain mode	
		11	Maximum gain mode	
Reserved	3	Reserved. Write as 0.		
	2:0	ALS time sets the photodiode chan	internal ADC integration tim	e for both
		FIELD VALUE	INTEGRATION TIME	MAX COUNT
		000	100 ms	36863
ATIME		001	200 ms	65535
		010	300 ms	65535
		011	400 ms	65535
		100	500 ms	65535
		101	600 ms	65535

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ALS Interrupt Threshold Register (0x04 - 0x0B)

The ALS interrupt threshold registers provide the values to be used as the high and low trigger points for the comparison function for interrupt generation. If CODATA crosses below the low threshold specified, or above the higher threshold, an interrupt is asserted on the interrupt pin.

If the CODATA exceeds the persist thresholds (registers: 0x04 -0x07) for the number of persist cycles configured in the PERSIST register an interrupt will be triggered. If the CODATA exceeds the no-persist thresholds (registers: 0x08 – 0x0B) an interrupt will be triggered immediately following the end of the current integration.

Note that while the interrupt is observable in the STATUS register (0x13), it is visible only on the INT pin when AIEN or NPIEN are enabled in the ENABLE register (0x00).

Upon power up, the interrupt threshold registers default to 0x00.

Register	Address	Bits	Description
AILTL	0x04	7:0	ALS low threshold lower byte
AILTH	0x05	7:0	ALS low threshold upper byte
AIHTL	0x06	7:0	ALS high threshold lower byte
AIHTH	0x07	7:0	ALS high threshold upper byte
NPAILTL	0x08	7:0	No Persist ALS low threshold lower byte
NPAILTH	0x09	7:0	No Persist ALS low threshold upper byte
NPAIHTL	0x0A	7:0	No Persist ALS high threshold lower byte
NPAIHTH	0x0B	7:0	No Persist ALS high threshold upper byte

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PERSIST Register (0x0C)

The Interrupt persistence filter sets the number of consecutive out-of-range ALS cycles necessary to generate an interrupt. Out-of-range is determined by comparing C0DATA (0x14 and 0x15) to the interrupt threshold registers (0x04 - 0x07). Note that the no-persist ALS interrupt is not affected by the interrupt persistence filter. Upon power up, the interrupt persistence filter register resets to 0x00.

7	6	5	4	3	2	1	0
Reserved			AP	ERS			

Field	Bits		Description			
Reserved	7:4	Reserved. Write as 0.	Reserved. Write as 0.			
		ALS interrupt persistence	ALS interrupt persistence filter			
		FIELD VALUE	PERSISTENCE			
		0000	Every ALS cycle generates an interrupt			
		0001	Any value outside of threshold range			
		0010	2 consecutive values out of range			
		0011	3 consecutive values out of range			
		0100	5 consecutive values out of range			
		0101	10 consecutive values out of range			
APERS	3:0	0110	15 consecutive values out of range			
APENS	3.0	0111	20 consecutive values out of range			
		1000	25 consecutive values out of range			
		1001	30 consecutive values out of range			
		1010	35 consecutive values out of range			
		1011	40 consecutive values out of range			
		1100	45 consecutive values out of range			
		1101	50 consecutive values out of range			
		1110	55 consecutive values out of range			
		1111	60 consecutive values out of range			

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PID Register (0x11)

The PID register provides an identification of the devices package. This register is a read-only register whose value never changes.

4 7 6 5 3 2 1 0 Reserved **PACKAGEID** Reserved

L			
	Field	Bits	Description
Ī	Reserved	7:6	Reserved.

Fleid	Bits	Description
Reserved	7:6	Reserved.
PID	5:4	Package Identification = 00
Reserved	3:0	Reserved.

ID Register (0x12)

The ID register provides the device identification. This register is a read-only register whose value never changes.

7 5 4 2 6 1 0

ID

Field	Bits	Description
ID	7:0	Device Identification = 0x50

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Status Register (0x13)

The Status Register provides the internal status of the device. This register is read only.

 7
 6
 5
 4
 3
 2
 1
 0

 Reserved
 NPINTR
 AINT
 Reserved
 AVALID

Field	Bits	Description	
Reserved	7:6	Reserved. Write at zero.	
NPINTR	5	No-persist Interrupt. Indicates that the device has encountered a no-persist interrupt condition.	
AINT	4	ALS Interrupt. Indicates that the device is asserting an ALS interrupt.	
Reserved	3:1	Reserved.	
AVALID	0	ALS Valid. Indicates that the ADC channels have completed an integration cycle since the AEN bit was asserted.	

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ALS Data Register (0x14 - 0x17)

ALS data is stored as two 16-bit values; one for each channel. When the lower byte of either channel is read, the upper byte of the same channel is latched into a shadow register. The shadow register ensures that both bytes are the result of the same ALS integration cycle, even if additional integration cycles occur between the lower byte and upper byte register readings. Each channel independently operates the upper byte shadow register. So to minimize the potential for skew between CHO and CH1 data, it is recommended to read all four ADC bytes in sequence.

Register	Address	Bits	Description
CODATAL	0x14	7:0	ALS CH0 data low byte
CODATAH	0x15	7:0	ALS CH0 data high byte
C1DATAL	0x16	7:0	ALS CH1 data low byte
C1DATAH	0x17	7:0	ALS CH1 data high byte

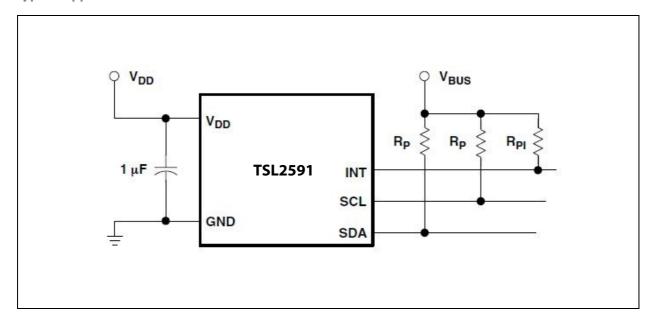
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Application Information

Figure 16 shows a typical hardware application circuit. A 1- μ F low-ESR decoupling capacitor should be placed as close as possible to the V_{DD} pin. V_{BUS} in this figure refers to the I^2C bus voltage, which is equal to V_{DD} .

Figure 16:
Typical Application Hardware Circuit



The I²C signals and the Interrupt are open-drain outputs and require pull-up resistors. The pull-up resistor (RP) value is a function of the I²C bus speed, the I²C bus voltage, and the capacitive load. The **ams** EVM running at 400 kbps, uses 1.5-k Ω resistors. A 10-k Ω pull-up resistor (RPI) can be used for the interrupt line.

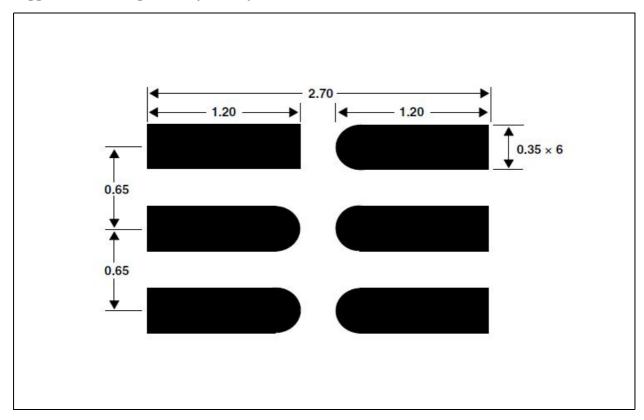
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PCB Pad Layout

Suggested land pattern based on the IPC-7351B Generic Requirements for Surface Mount Design and Land Pattern Standard (2010) for the small outline no-lead (SON) package is shown in Figure 17.

Figure 17:
Suggested FN Package PCB Layout (Top View)



Note(s):

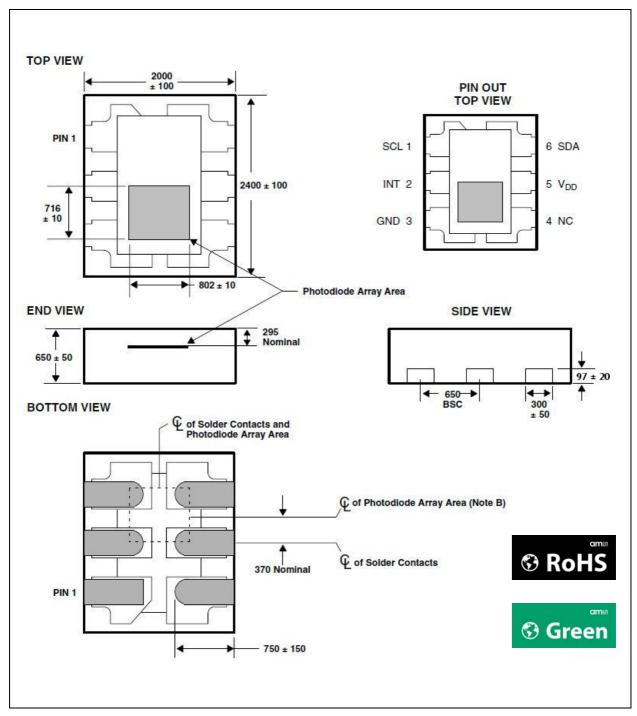
- 1. All linear dimensions are in millimeters.
- 2. This drawing is subject to change without notice.

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Package Drawings & Markings

Figure 18: FN Package – Dual Flat No-Lead Packaging Configuration



Note(s):

- 1. All linear dimensions are in micrometers.
- 2. The die is centered within the package within a tolerence of $\pm 75~\mu\text{m}.$
- 3. Package top surface is molded with an electrically non-conductive clear plastic compound having an index of refraction of 1.55.
- 4. Contact finish is copper alloy A194 with pre-plated NiPdAu lead finish.
- 5. This package contains no lead (Pb).
- 6. This drawing is subject to change without notice.

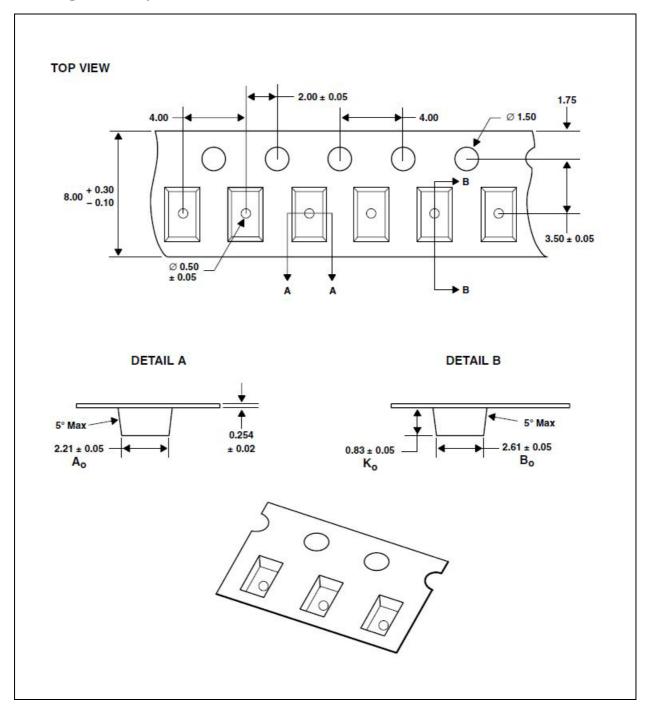
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Mechanical Data

Figure 19: FN Package Carrier Tape and Reel Information



Note(s):

- 1. All linear dimensions are in millimeters. Dimension tolerance is \pm 0.10 mm unless otherwise noted.
- 2. The dimensions on this drawing are for illustrative purposes only. Dimensions of an actual carrier may vary slightly.
- 3. Symbols on drawing A_O , B_O and K_O are defined in ANSI EIA Standard 481-B 2001.
- 4. Each reel is 178 millimeters in diameter and contains 3500 parts.
- 5. ams packaging tape and reel conform to the requirements of EIA Standard 481 B.
- 6. In accordance with EIA Standard, device pin 1 is located next to the sprocket holes in the tape.
- 7. This drawing is subject to change without notice.

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Soldering Information

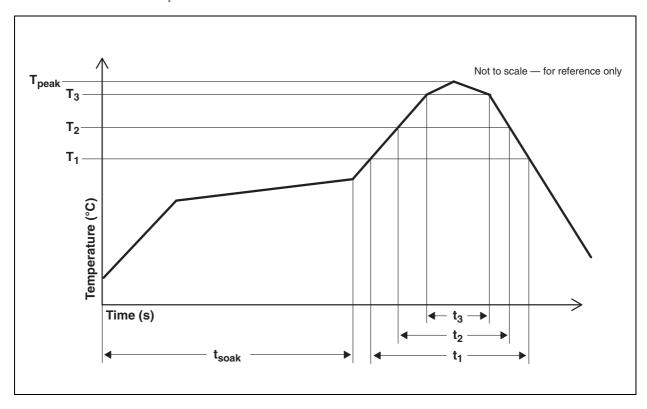
The package has been tested and has demonstrated an ability to be reflow soldered to a PCB substrate.

The solder reflow profile describes the expected maximum heat exposure of components during the solder reflow process of product on a PCB. Temperature is measured on top of component. The components should be limited to a maximum of three passes through this solder reflow profile.

Figure 20: Solder Reflow Profile

Parameter	Reference	Device
Average temperature gradient in preheating		2.5 °C/s
Soak time	t _{soak}	2 to 3 minutes
Time above 217 °C (T₁)	t ₁	Max 60 s
Time above 230 °C (T ₂)	t ₂	Max 50 s
Time above T _{peak} - 10 °C (T ₃)	t ₃	Max 10 s
Peak temperature in reflow	T _{peak}	260 ℃
Temperature gradient in cooling		Max -5 °C/s

Figure 21: Solder Reflow Profile Graph



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Storage Information

Moisture Sensitivity

Optical characteristics of the device can be adversely affected during the soldering process by the release and vaporization of moisture that has been previously absorbed into the package. To ensure the package contains the smallest amount of absorbed moisture possible, each device is baked prior to being dry packed for shipping.

Devices are dry packed in a sealed aluminized envelope called a moisture-barrier bag with silica gel to protect them from ambient moisture during shipping, handling, and storage before use.

Shelf Life

The calculated shelf life of the device in an unopened moisture barrier bag is 12 months from the date code on the bag when stored under the following conditions:

· Shelf Life: 12 months

• Ambient Temperature: $< 40^{\circ}C$

• Relative Humidity: < 90%

Rebaking of the devices will be required if the devices exceed the 12 month shelf life or the Humidity Indicator Card shows that the devices were exposed to conditions beyond the allowable moisture region.

Floor Life

The FN package has been assigned a moisture sensitivity level of MSL 3. As a result, the floor life of devices removed from the moisture barrier bag is 168 hours from the time the bag was opened, provided that the devices are stored under the following conditions:

• Floor Life: 168 hours

• Ambient Temperature: < 30°C

• Relative Humidity: < 60%

If the floor life or the temperature/humidity conditions have been exceeded, the devices must be rebaked prior to solder reflow or dry packing.

Rebaking Instructions

When the shelf life or floor life limits have been exceeded, rebake at 50°C for 12 hours.

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Ordering & Contact Information

Figure 22: Ordering Information

Ordering Code	Address	Interface	Delivery Form
TSL25911FN	0x29	$I^2CV_{bus} = V_{DD}$ Interface	ODFN-6
TSL25913FN	0x29	$I^2CV_{bus} = 1.8V$	ODFN-6

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Document Status

Document Status	Product Status	Definition
Product Preview	Pre-Development	Information in this datasheet is based on product ideas in the planning phase of development. All specifications are design goals without any warranty and are subject to change without notice
Preliminary Datasheet	Pre-Production	Information in this datasheet is based on products in the design, validation or qualification phase of development. The performance and parameters shown in this document are preliminary without any warranty and are subject to change without notice
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Datasheet (discontinued)	Discontinued	Information in this datasheet is based on products which conform to specifications in accordance with the terms of ams AG standard warranty as given in the General Terms of Trade, but these products have been superseded and should not be used for new designs

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Revision Information

Changes from 2-03 (2018-Apr-30) to current revision 2-04 (2018-Jun-05)	Page
Updated Figure 5	5
Updated text under Electrical Characteristics	6

Note(s):

- 1. Page and figure numbers for the previous version may differ from page and figure numbers in the current revision.
- 2. Correction of typographical errors is not explicitly mentioned.

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